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IESL/FORTH
 III-Nitrides
 Microcavities
 Electrochemistry of Semiconductors
 Intersubband Optoelectronics

	Όλα	Από το 2016
Παραθέσεις	267	178
h-index	5	4
i10-index	5	3

ΤΙΤΛΟΣ	ΠΑΡΑΤΙΘΕΤΑΙ ΑΠΟ	ΈΤΟΣ
III-nitride semiconductors for intersubband optoelectronics: a review M Beeler, E Trichas, E Monroy Semiconductor science and technology 28 (7), 074022	159	2013
All-dielectric GaN microcavity: Strong coupling and lasing at room temperature KS Daskalakis, PS Eldridge, G Christmann, E Trichas, R Murray, ... Applied Physics Letters 102 (10), 101113	55	2013
Resonantly enhanced selective photochemical etching of GaN E Trichas, M Kayambaki, E Iliopoulos, NT Pelekanos, PG Savvidis Applied Physics Letters 94 (17), 173505	25	2009
Selective photochemical etching of GaN films and laser lift-off for microcavity fabrication E Trichas, C Xenogianni, M Kayambaki, P Tsotsis, E Iliopoulos, ... physica status solidi (a) 205 (11), 2509-2512	14	2008
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Anti-binding of biexcitons in (2 1 1) B InAs/GaAs piezoelectric quantum dots GE Dialynas, C Xenogianni, S Tsintzos, E Trichas, PG Savvidis, ... Physica E: Low-dimensional Systems and Nanostructures 40 (6), 2113-2115		2008
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